

PS9313L, PS9313L2

1 Mbps, OPEN COLLECTOR OUTPUT TYPE,
HIGH CMR, INTELLIGENT POWER MODULE DRIVE
8 mm CREEPAGE 6-PIN SDIP PHOTOCOUPLER

R08DS0125EJ0200
Rev.2.00
Apr 13, 2015

Description

The PS9313L and PS9313L2 are optical coupled isolators containing a GaAlAs LED on the input side and a photo diode and a signal processing circuit on the output side on one chip.

The PS9313L and PS9313L2 are specified high CMR, high CTR and pulse width distortion with operating temperature. It is suitable for IPM drive.

The PS9313L is lead bending type (Gull-wing) for surface mounting.

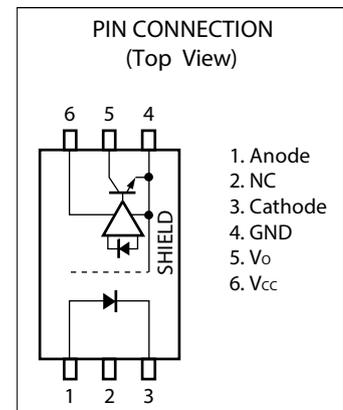
The PS9313L2 is lead bending type for long creepage distance (Gull-wing) for surface mount.

Features

- High common mode transient immunity ($CM_H, CM_L = \pm 15 \text{ kV}/\mu\text{s MIN.}$)
- Half size of 8-pin DIP
- Long creepage distance (8 mm MIN. : PS9313L2)
- High-speed response ($t_{PHL} = 500 \text{ ns MAX.}, t_{PLH} = 750 \text{ ns MAX.}$)
- Maximum propagation delays ($t_{PLH} - t_{PHL} = 220 \text{ ns TYP.}$)
- Pulse width distortion ($|t_{PHL} - t_{PLH}| = 220 \text{ ns TYP.}$)
- High isolation voltage ($BV = 5\,000 \text{ Vr.m.s.}$)
- Open collector output
- Pb-Free product
- Safety standards
 - UL approved: No. E72422
 - CSA approved: No. CA 101391 (CA5A, CAN/CSA-C22.2 60065, 60950)
 - SEMKO approved (EN 60065, EN 60950)
 - DIN EN60747-5-5 (VDE0884-5):2011-11 approved: No. 40024069 (Option)

APPLICATIONS

- IPM Driver
- General purpose inverter

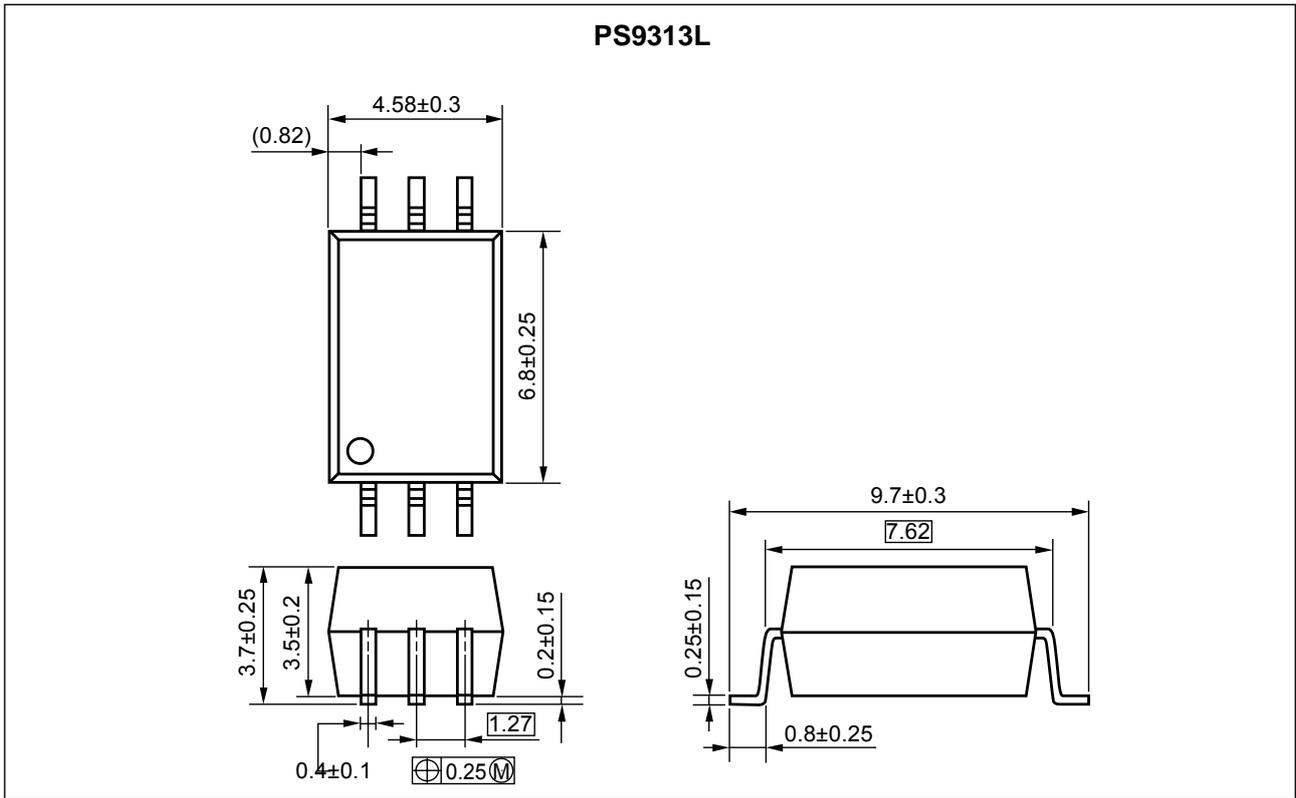


TRUTH TABLE

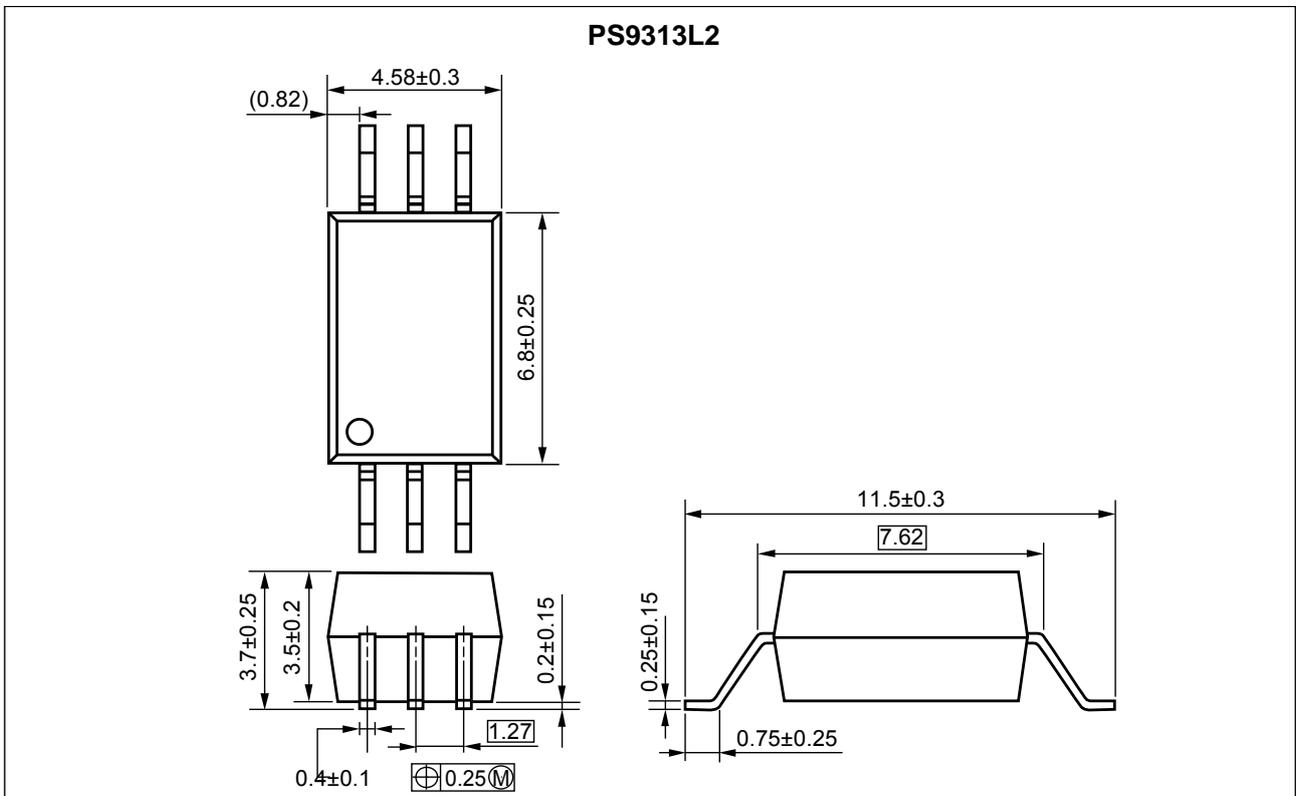
LED	Output
ON	L
OFF	H

PACKAGE DIMENSIONS (UNIT: mm)

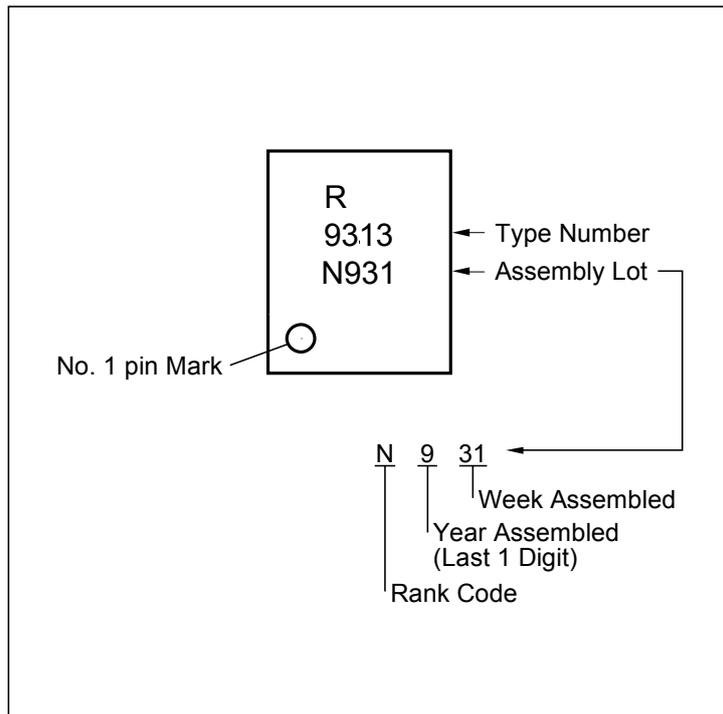
- Lead Bending Type (Gull-wing) For Surface Mount



- Lead Bending Type For Long Creepage Distance (Gull-wing) For Surface Mount



MARKING EXAMPLE



MARKING EXAMPLE

Parameter	PS9313L	PS9313L2
Air Distance (MIN.)	7 mm	8 mm
Outer Creepage Distance (MIN.)	7 mm	8 mm
Isolation Distance (MIN.)	0.4 mm	0.4 mm

ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number ^{*1}	
PS9313L	PS9313L-AX	Pb-Free (Ni/Pd/Au)	20 pcs (Tape 20 pcs cut)	Standard products (UL, CSA approved)	PS9313L	
PS9313L-E3	PS9313L-E3-AX		Embossed Tape 2 000 pcs/reel			
PS9313L2	PS9313L2-AX		20 pcs (Tape 20 pcs cut)		DIN EN60747-5-5 (VDE0884-5):2011-11	PS9313L2
PS9313L2-E3	PS9313L2-E3-AX		Embossed Tape 2 000 pcs/reel			
PS9313L-V	PS9313L-V-AX		20 pcs (Tape 20 pcs cut)	Approved (Option)	PS9313L	
PS9313L-V-E3	PS9313L-V-E3-AX		Embossed Tape 2 000 pcs/reel			
PS9313L2-V	PS9313L2-V-AX		20 pcs (Tape 20 pcs cut)		Approved (Option)	PS9313L2
PS9313L2-V-E3	PS9313L2-V-E3-AX		Embossed Tape 2 000 pcs/reel			

Notes*: 1. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current*1	I _F	25	mA
	Reverse Voltage	V _R	5	V
Detector	Supply Voltage	V _{CC}	-0.5 to +25	V
	Output Voltage	V _O	-0.5 to +25	V
	Output Current	I _O	15	mA
	Power Dissipation*2	P _C	100	mW
Isolation Voltage*3		BV	5 000	Vr.m.s.
Operating Ambient Temperature		T _A	-40 to +110	°C
Storage Temperature		T _{stg}	-55 to +125	°C

Notes*: 1. Reduced to 0.3 mA/°C at T_A = 70°C or more.

2. Reduced to 2.0 mW/°C at T_A = 70°C or more.

3. AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output.

Pins 1-3 shorted together, 4-6 shorted together.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	V _{CC}	4.5	15	20	V
Output Voltage	V _O	0		20	V
Forward Current (ON)	I _{F (ON)}	8		12	mA
Forward Voltage (OFF)	V _{F (OFF)}	0		0.8	V

ELECTRICAL CHARACTERISTICS (T_A = -40 to +110°C, V_{CC} = 15 V, unless otherwise specified)

Parameter		Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Diode	Forward Voltage	V _F	I _F = 10 mA, T _A = 25°C	1.2	1.56	1.9	V
	Reverse Current	I _R	V _R = 3 V, T _A = 25°C			10	μA
	Terminal Capacitance	C _t	V = 0 V, f = 1 MHz		30		pF
Detector	Low Level Output Voltage	V _{OL}	I _F = 10 mA, I _{OL} = 2.4 mA		0.13	0.6	V
	High Level Output Current	I _{OH}	V _{CC} = 20 V, V _F = 0.8 V		1.0	50	μA
	High Level Supply Current	I _{CCH}	V _{CC} = 20 V, V _F = 0.8 V, V _O = open		0.6	1.3	mA
	Low Level Supply Current	I _{CCL}	V _{CC} = 20 V, I _F = 10 mA, V _O = open		0.7	1.3	mA
Coupled	Threshold Input Current (H → L)	I _{FHL}	V _O = 0.8 V, I _O = 0.75 mA		0.75	5.0	mA
	Current Transfer Ratio (I _C /I _F)	CTR	I _F = 10 mA, V _O = 0.6 V	44	110		%
	Isolation Resistance	R _{I-O}	V _{I-O} = 1 kV _{DC}	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz		0.7		pF
	Propagation Delay Time (H → L) ^{*2}	t _{PHL}	I _F = 10 mA, R _L = 20 kΩ, C _L = 100 pF, V _{THHL} = 1.5 V, V _{THLH} = 2.0 V		240	500	ns
	Propagation Delay Time (L → H) ^{*2}	t _{PLH}			460	750	
	Maximum Propagation Delays	t _{PLH} -t _{PHL}		-200	220	650	
	Pulse Width Distortion (PWD)	t _{PHL} -t _{PLH}			220	650	
	Common Mode Transient Immunity at High Level Output ^{*3}	CM _H		T _A = 25°C, I _F = 0 mA, V _O > 3.0 V, V _{CM} = 1.5 kV, R _L = 20 kΩ, C _L = 100 pF	15		
Common Mode Transient Immunity at Low Level Output ^{*3}	CM _L	T _A = 25°C, I _F = 10 mA, V _O < 1.0 V, V _{CM} = 1.5 kV, R _L = 20 kΩ, C _L = 100 pF	15			kV/μs	

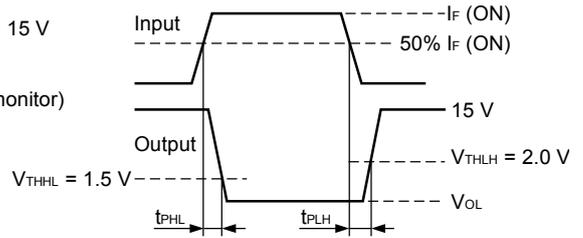
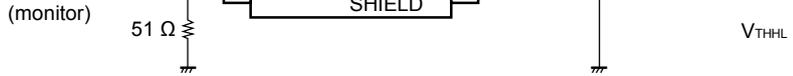
Notes*: 1. Typical values at $T_A = 25^\circ\text{C}$.

2. Test circuit for propagation delay time

Pulse input ($I_F = 10\text{ mA}$)

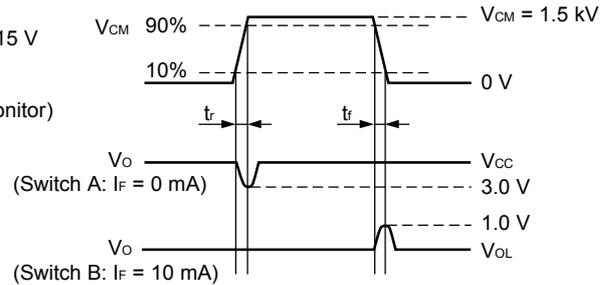
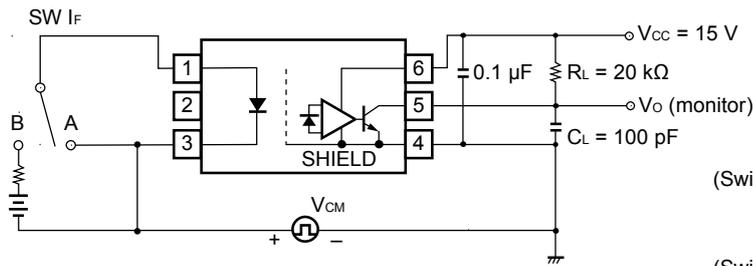
($PW = 10\ \mu\text{s}$,
Duty cycle = 1/10)

Input
(monitor)



Remark C_L includes probe and stray wiring capacitance.

3. Test circuit for common mode transient immunity



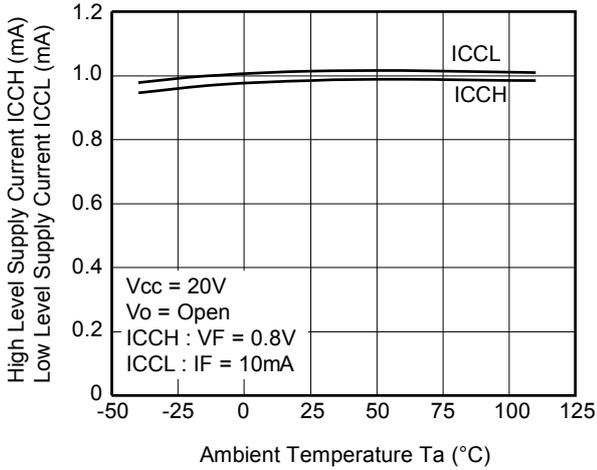
Remark C_L includes probe and stray wiring capacitance.

USAGE CAUTIONS

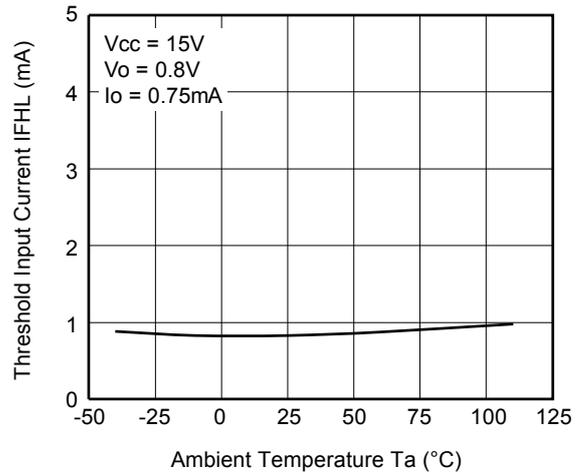
1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
2. By-pass capacitor of more than $0.1\ \mu\text{F}$ is used between V_{CC} and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
3. Pin 2 (which is an NC^{*1} pin) can either be connected directly to the GND pin on the LED side or left open. Unconnected pins should not be used as a bypass for signals or for any other similar purpose because this may degrade the internal noise environment of the device.
*1 NC: Not connected (No connection)
4. Avoid storage at a high temperature and high humidity.

TYPICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

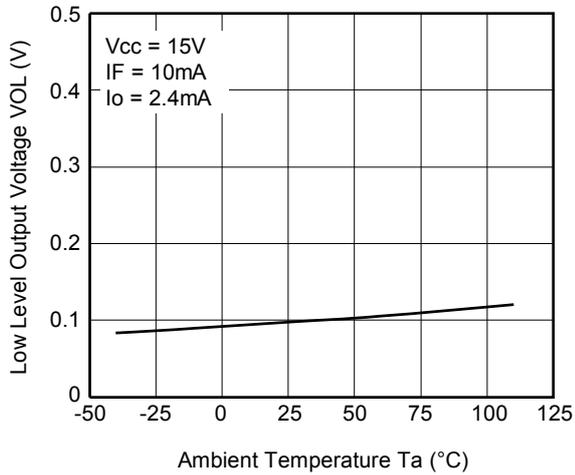
SUPPLY CURRENT vs. AMBIENT TEMPERATURE



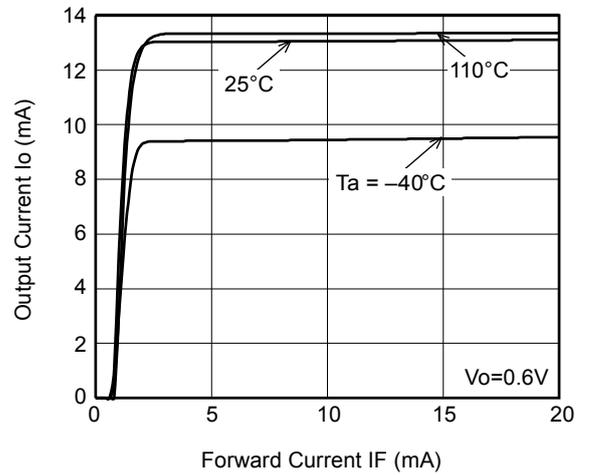
THRESHOLD INPUT CURRENT vs. AMBIENT TEMPERATURE



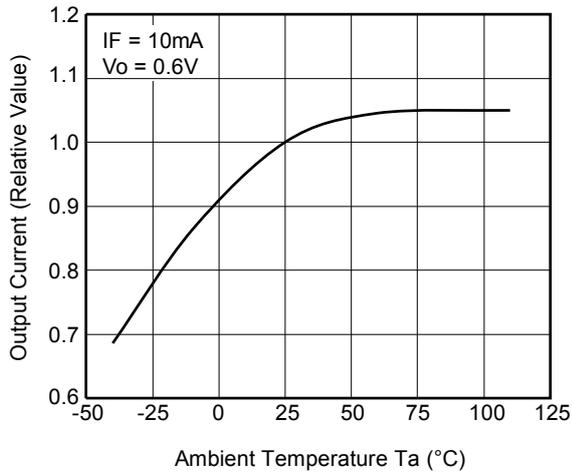
LOW LEVEL OUTPUT VOLTAGE vs. AMBIENT TEMPERATURE



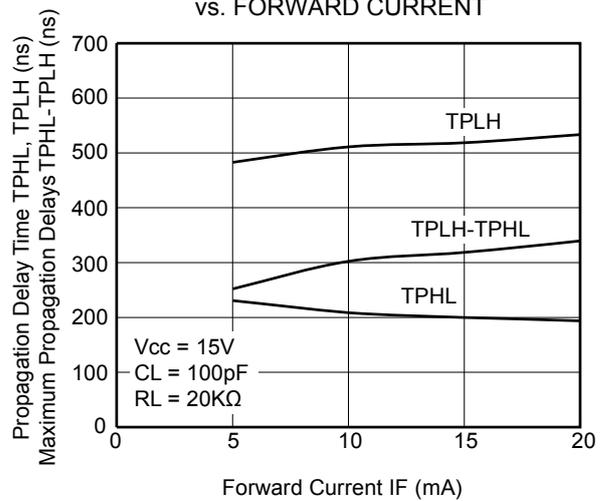
OUTPUT CURRENT vs. FORWARD CURRENT



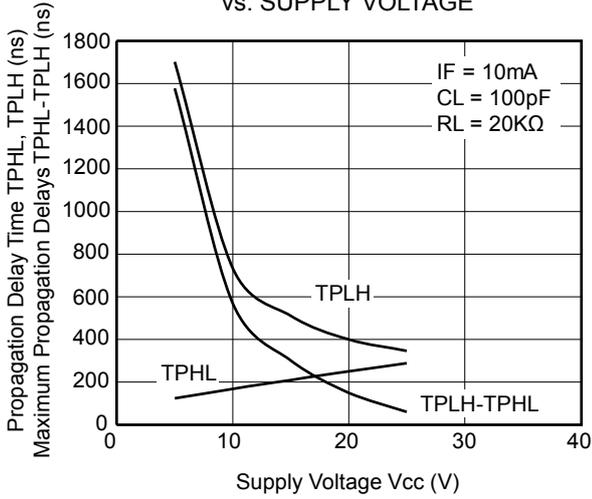
OUTPUT CURRENT vs. AMBIENT TEMPERATURE



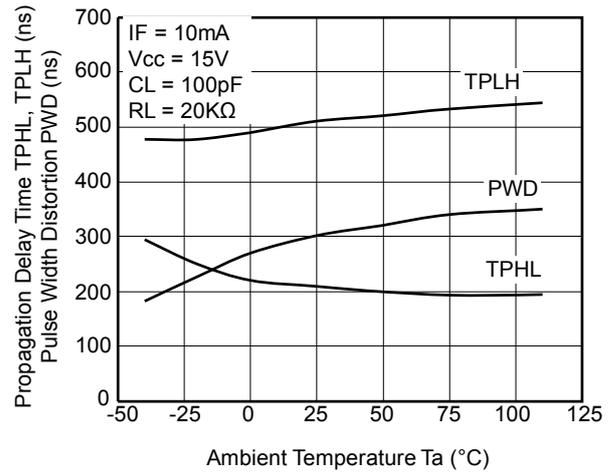
PROPAGATION DELAY TIME, MAXIMUM PROPAGATION DELAYS vs. FORWARD CURRENT



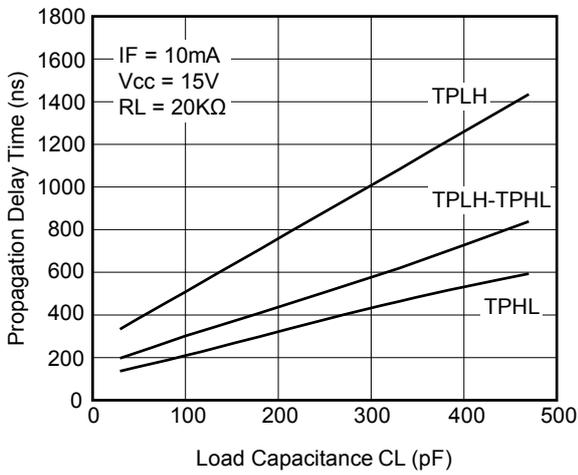
PROPAGATION DELAY TIME,
MAXIMUM PROPAGATION DELAYS
vs. SUPPLY VOLTAGE



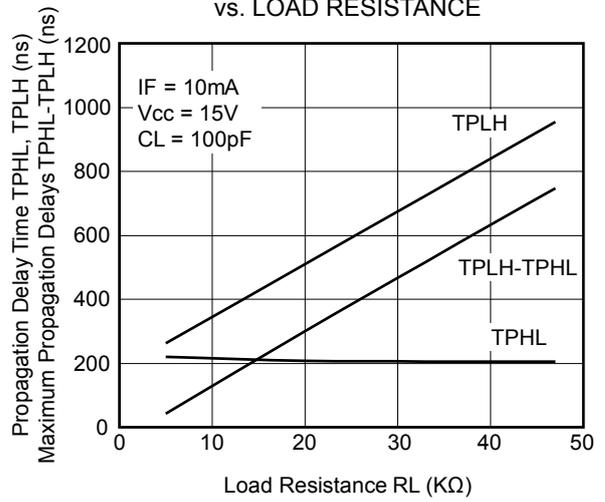
PROPAGATION DELAY TIME,
PULSE WIDTH DISTORTION
vs. AMBIENT TEMPERATURE



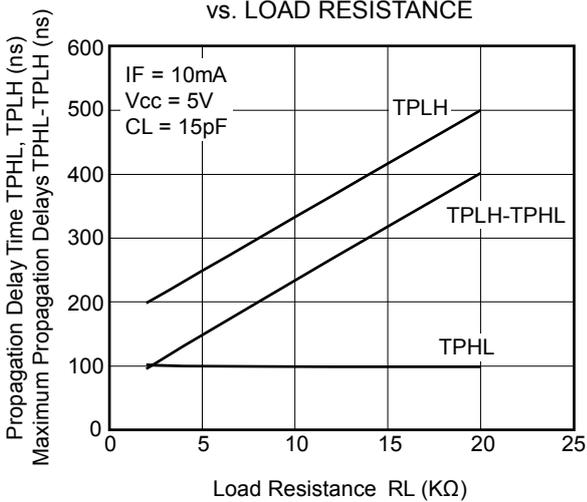
PROPAGATION DELAY TIME
vs. LOAD CAPACITANCE



PROPAGATION DELAY TIME,
MAXIMUM PROPAGATION DELAYS
vs. LOAD RESISTANCE

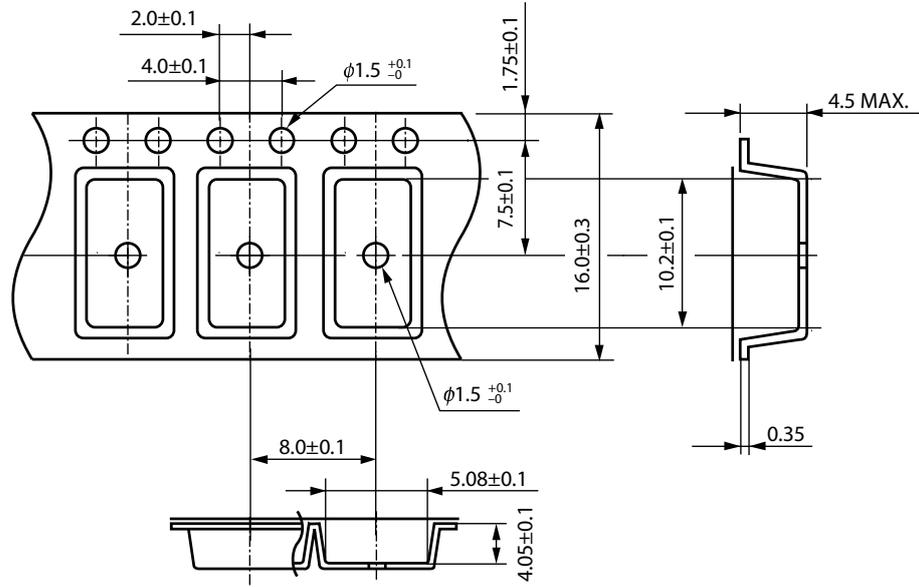


PROPAGATION DELAY TIME,
MAXIMUM PROPAGATION DELAYS
vs. LOAD RESISTANCE

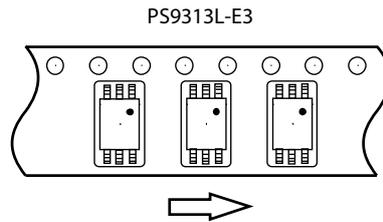


TAPING SPECIFICATIONS (UNIT: mm)

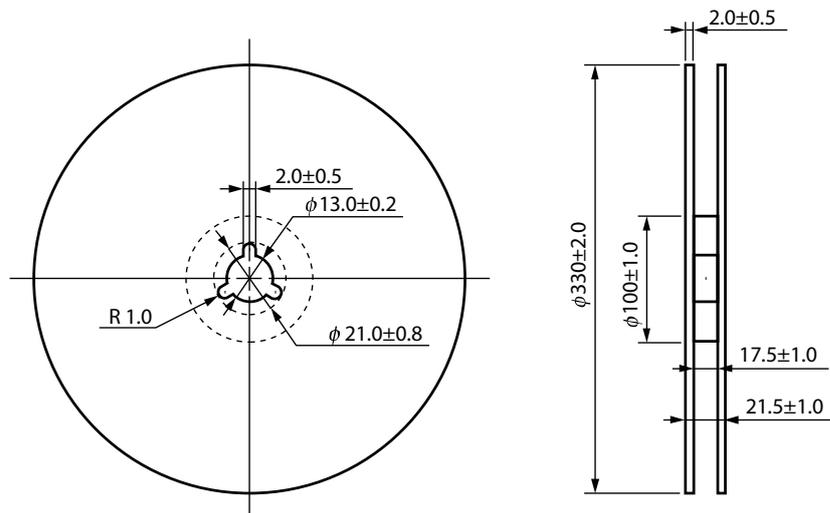
Outline and Dimensions (Tape)



Tape Direction

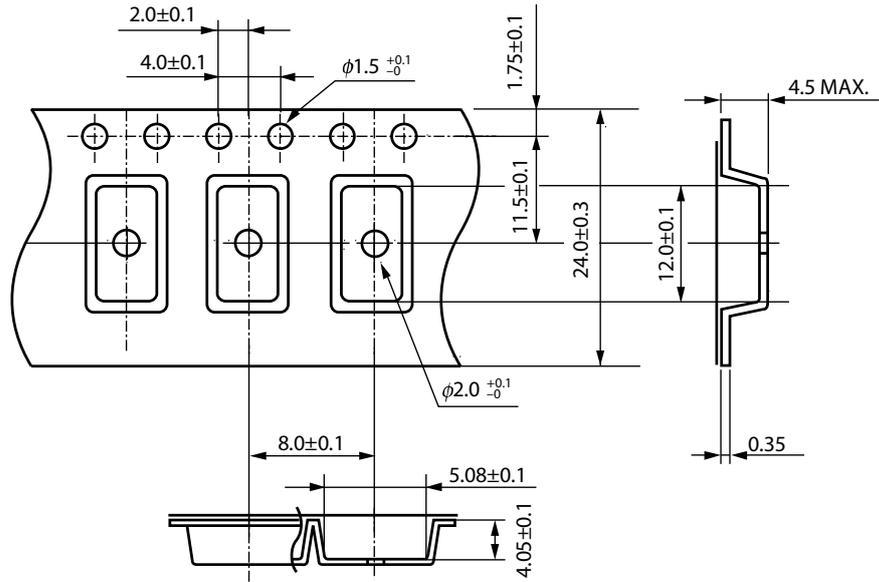


Outline and Dimensions (Reel)

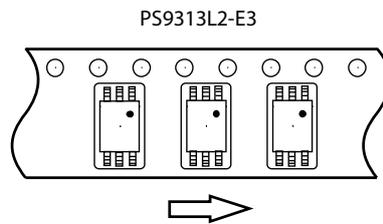


Packing: 2 000 pcs/reel

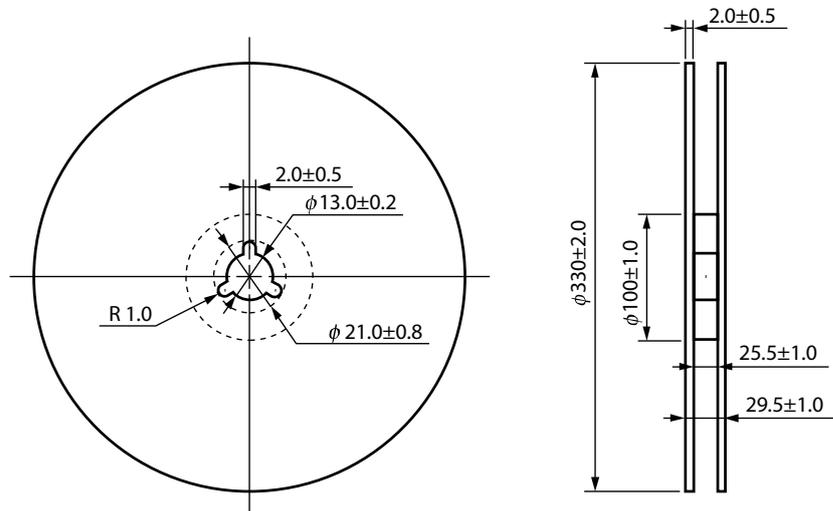
Outline and Dimensions (Tape)



Tape Direction

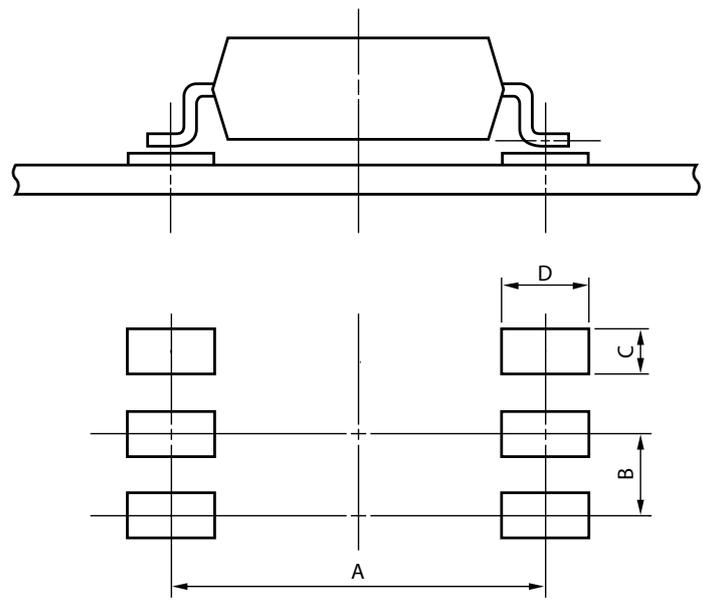


Outline and Dimensions (Reel)



Packing: 2 000 pcs/reel

RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Part Number	Lead Bending	A	B	C	D
PS9313L	lead bending type (Gull-wing) for surface mount	9.2	1.27	0.8	2.2
PS9313L2	lead bending type (Gull-wing) for long creepage distance (surface mount)	10.2	1.27	0.8	2.2

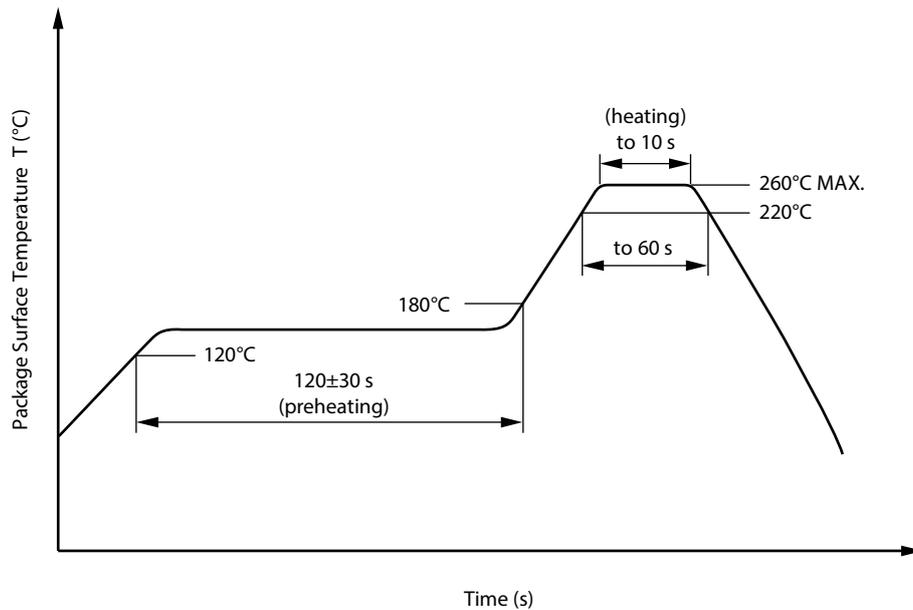
NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

- Peak reflow temperature 260°C or below (package surface temperature)
- Time of peak reflow temperature 10 seconds or less
- Time of temperature higher than 220°C 60 seconds or less
- Time to preheat temperature from 120 to 180°C 120±30 s
- Number of reflows Three
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

- Peak Temperature (lead part temperature) 350°C or below
- Time (each pins) 3 seconds or less
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(b) Please be sure that the temperature of the package would not be heated over 100°C

(4) Cautions

- Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Spec.	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/110/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.6 \times U_{IORM}$, $P_d < 5$ pC	U_{IORM} U_{pr}	1 130 1 808	V_{peak} V_{peak}
Test voltage (partial discharge test, procedure b for all devices) $U_{pr} = 1.875 \times U_{IORM}$, $P_d < 5$ pC	U_{pr}	2 119	V_{peak}
Highest permissible overvoltage	U_{TR}	8 000	V_{peak}
Degree of pollution (DIN EN 60664-1 VDE 0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	175	
Material group (DIN EN 60664-1 VDE 0110 Part 1)		III a	
Storage temperature range	T_{stg}	-55 to +125	°C
Operating temperature range	T_A	-40 to +110	°C
Isolation resistance, minimum value $V_{IO} = 500$ V dc at $T_A = 25^\circ\text{C}$ $V_{IO} = 500$ V dc at T_A MAX. at least 100°C	Ris MIN. Ris MIN.	10^{12} 10^{11}	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve)			
Package temperature	T_{si}	175	°C
Current (input current I_F , $P_{si} = 0$)	I_{si}	400	mA
Power (output or total power dissipation)	P_{si}	700	mW
Isolation resistance $V_{IO} = 500$ V dc at $T_A = T_{si}$	Ris MIN.	10^9	Ω

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

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